TEXAS INSTRUMENTS

SCCS018 - May 1994 - Revised February 2000

CY54/74FCT245T

8-Bit Transceiver

Features

- **Function, pinout, and drive compatible with FCT, and F logic**
- **FCT-D speed at 3.8 ns max. (Com'l),**
  FCT-C speed at 4.1 ns max. (Com'l),
  FCT-A speed at 4.6 ns max. (Com'l)
- **Reduced V_{OH} (typically = 3.3V) versions of equivalent FCT functions**
- **Edge-rate control circuitry for significantly improved noise characteristics**
- **Power-off disable feature**
- **ESD > 2000V**
- **Matched rise and fall times**
- **Fully compatible with TTL input and output logic levels**
- **Extended commercial range of −40˚C to +85˚C**
- **Sink current   64 mA (Com'l), 48 mA (Mil)**
 **Source current   32 mA (Com'l), 12 mA (Mil)**

Functional Description

The FCT245T contains eight non-inverting bidirectional buffers with three-state outputs and is intended for bus oriented applications. For the FCT245T, current sinking capability is 64 mA at the A and B ports.

The Transmit/Receiver (T/$\overline{R}$) input determines the direction of data flow through bidirectional transceiver. Transmit (Active HIGH) enables data from A ports to B ports. The output enable ($\overline{OE}$), when HIGH, disables both the A and B ports by putting them in a High Z condition.

The outputs are designed with a power-off disable feature to allow for live insertion of boards.

Logic Block Diagram
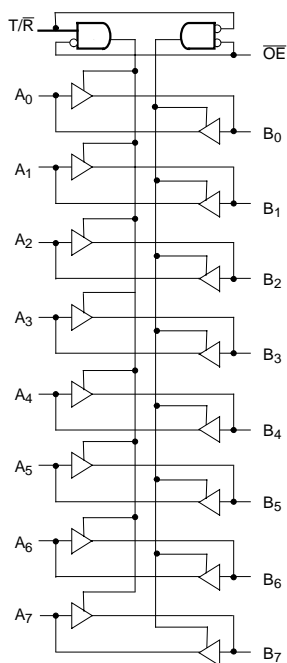
Pin Configurations
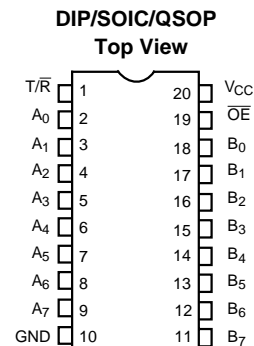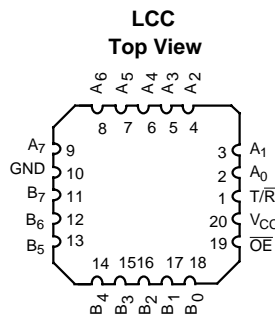
Function Table[1]

$\overline{OE}$	T/$\overline{R}$	Operation
L	L	B Data to Bus A
L	H	A Data to Bus B
H	X	High Z State

Note:
1. H = HIGH Voltage Level. L = LOW Voltage Level. X = Don't Care.

TEXAS INSTRUMENTS

Maximum Ratings[2,3]

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature ....−65°C to +150°C

Ambient Temperature with
Power Applied...−65°C to +135°C

Supply Voltage to Ground Potential..................−0.5V to +7.0V

DC Input Voltage ....−0.5V to +7.0V

DC Output Voltage ....−0.5V to +7.0V

DC Output Current (Maximum Sink Current/Pin).......120 mA

Power Dissipation 0.5W

Static Discharge Voltage...>2001V
(per MIL-STD-883, Method 3015)

Operating Range

Range	Range	Ambient Temperature	V_{CC}
Commercial	DT	0°C to +70°C	5V ± 5%
Commercial	T, AT, CT	−40°C to +85°C	5V ± 5%
Military[4]	All	−55°C to +125°C	5V ± 10%

Electrical Characteristics Over the Operating Range

Parameter	Description	Test Conditions		Min.	Typ.[5]	Max.	Unit
V_{OH}	Output HIGH Voltage	V_{CC}=Min., I_{OH}=−32 mA	Com'l	2.0			V
		V_{CC}=Min., I_{OH}=−15 mA	Com'l	2.4	3.3		V
		V_{CC}=Min., I_{OH}=−12 mA	Mil	2.4	3.3		V
V_{OL}	Output LOW Voltage	V_{CC}=Min., I_{OL}=64 mA	Com'l		0.3	0.55	V
		V_{CC}=Min., I_{OL}=48mA	Mil		0.3	0.55	V
V_{IH}	Input HIGH Voltage			2.0			V
V_{IL}	Input LOW Voltage					0.8	V
V_H	Hysteresis[6]	All inputs			0.2		V
V_{IK}	Input Clamp Diode Voltage	V_{CC}=Min., I_{IN}=−18 mA			−0.7	−1.2	V
I_I	Input HIGH Current	V_{CC}=Max., V_{IN}=V_{CC}				5	µA
I_{IH}	Input HIGH Current	V_{CC}=Max., V_{IN}=2.7V				±1	µA
I_{IL}	Input LOW Current	V_{CC}=Max., V_{IN}=0.5V				±1	µA
I_{OS}	Output Short Circuit Current[7]	V_{CC}=Max., V_{OUT}=0.0V		−60	−120	−225	mA
I_{OFF}	Power-Off Disable	V_{CC}=0V, V_{OUT}=4.5V				±1	µA

Capacitance[6]

Parameter	Description	Typ.[5]	Max.	Unit
C_{IN}	Input Capacitance	5	10	pF
C_{OUT}	Output Capacitance	9	12	pF

Notes:
2. Unless otherwise noted, these limits are over the operating free-air temperature range.
3. Unused inputs must always be connected to an appropriate logic voltage level, preferably either V_{CC} or ground.
4. T_A is the "instant on" case temperature.
5. Typical values are at V_{CC}=5.0V, T_A=+25˚C ambient.
6. This parameter is specified but not tested.
7. Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high-speed test apparatus and/or sample and hold techniques are preferable in order to minimize internal chip heating and more accurately reflect operational values. Otherwise prolonged shorting of a high output may raise the chip temperature well above normal and thereby cause invalid readings in other parametric tests. In any sequence of parameter tests, I_{OS} tests should be performed last.

Power Supply Characteristics

Parameter	Description	Test Conditions	Typ.[5]	Max.	Unit
I_{CC}	Quiescent Power Supply Current	V_{CC}=Max., V_{IN}≤0.2V, V_{IN}≥V_{CC}−0.2V	0.1	0.2	mA
ΔI_{CC}	Quiescent Power Supply Current (TTL inputs HIGH)	V_{CC}=Max., V_{IN}=3.4V,[8] f_1=0, Outputs Open	0.5	2.0	mA
I_{CCD}	Dynamic Power Supply Current[9]	V_{CC}=Max., One Input Toggling, 50% Duty Cycle, Outputs Open, T/$\overline{R}$ or $\overline{OE}$=GND and V_{IN}≤0.2V or V_{IN}≥V_{CC}−0.2V	0.06	0.12	mA/MHz
I_C	Total Power Supply Current[10]	V_{CC}=Max., 50% Duty Cycle, Outputs Open, One Bit Toggling at f_1=10 MHz, T/$\overline{R}$ or $\overline{OE}$=GND and V_{IN}≤0.2V or V_{IN}≥V_{CC}−0.2V	0.7	1.4	mA
		V_{CC}=Max., 50% Duty Cycle, Outputs Open, One Bit Toggling at f_1=10 MHz, T/$\overline{R}$ or $\overline{OE}$=GND and V_{IN}=3.4V or V_{IN}=GND	1.2	3.4	mA
		V_{CC}=Max., 50% Duty Cycle, Outputs Open, Eight Bits Toggling at f_1=2.5 MHz, T/$\overline{R}$ or $\overline{OE}$=GND and V_{IN}≤0.2V or V_{IN}≥V_{CC}−0.2V	1.3	2.6[11]	mA
		V_{CC}=Max., 50% Duty Cycle, Outputs Open, Eight Bits Toggling at f_1=2.5 MHz, T/$\overline{R}$ or $\overline{OE}$=GND and V_{IN}=3.4V or V_{IN}=GND	3.3	10.6[11]	mA

Notes:
8. Per TTL driven input (V_{IN}=3.4V); all other inputs at V_{CC} or GND.
9. This parameter is not directly testable, but is derived for use in Total Power Supply calculations.
10. I_C = $I_{QUIESCENT}$ + I_{INPUTS} + $I_{DYNAMIC}$
    I_C = I_{CC}+$\Delta I_{CC}D_H N_T$+$I_{CCD}(f_0/2 + f_1 N_1)$
    I_{CC} = Quiescent Current with CMOS input levels
    ΔI_{CC} = Power Supply Current for a TTL HIGH input (V_{IN}=3.4V)
    D_H = Duty Cycle for TTL inputs HIGH
    N_T = Number of TTL inputs at D_H
    I_{CCD} = Dynamic Current caused by an input transition pair (HLH or LHL)
    f_0 = Clock frequency for registered devices, otherwise zero
    f_1 = Input signal frequency
    N_1 = Number of inputs changing at f_1
    All currents are in milliamps and all frequencies are in megahertz.
11. Values for these conditions are examples of the I_{CC} formula. These limits are specified but not tested.

Switching Characteristics Over the Operating Range

| | | FCT245T | | | | FCT245AT | | | | | |
| | | Military | | Commercial | | Military | | Commercial | | | |
Parameter	Description	Min.[12]	Max.	Min.[12]	Max.	Min.[12]	Max.	Min.[12]	Max.	Unit	Fig. No.[13]
t_{PLH} t_{PHL}	Propagation Delay A to B or B to A	1.5	7.5	1.5	7.0	1.5	4.9	1.5	4.6	ns	1, 3
t_{PZH} t_{PZL}	Output Enable Time $\overline{OE}$ or T/$\overline{R}$ to A or B	1.5	10.0	1.5	9.5	1.5	6.5	1.5	6.2	ns	1, 7, 8
t_{PHZ} t_{PLZ}	Output Disable Time $\overline{OE}$ or T/$\overline{R}$ to A or B	1.5	10.0	1.5	7.5	1.5	6.0	1.5	5.0	ns	1, 7, 8

Switching Characteristics Over the Operating Range (continued)

| | | FCT245CT | | | | FCT245DT | | | |
| | | Military | | Commercial | | Commercial | | | |
Parameter	Description	Min.[12]	Max.	Min.[12]	Max.	Min.[12]	Max.	Unit	Fig. No.[13]
t_{PLH} t_{PHL}	Propagation Delay A to B or B to A	1.5	4.5	1.5	4.1	1.5	3.8	ns	1, 3
t_{PZH} t_{PZL}	Output Enable Time $\overline{OE}$ or T/$\overline{R}$ to A or B	1.5	6.2	1.5	5.8	1.5	5.0	ns	1, 7, 8
t_{PHZ} t_{PLZ}	Output Disable Time $\overline{OE}$ or T/$\overline{R}$ to A or B	1.5	5.2	1.5	4.8	1.5	4.3	ns	1, 7, 8

Ordering Information

| Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
3.8	CY74FCT245DTQCT	Q5	20-Lead (150-Mil) QSOP	Commercial
	CY74FCT245DTSOC/SOCT	S5	20-Lead (300-Mil) Molded SOIC	
4.1	CY74FCT245CTQCT	Q5	20-Lead (150-Mil) QSOP	Commercial
	CY74FCT245CTSOC/SOCT	S5	20-Lead (300-Mil) Molded SOIC	
4.5	CY54FCT245CTDMB	D6	20-Lead (300-Mil) CerDIP	Military
	CY54FCT245CTLMB	L61	20-Square Leadless Chip Carrier	
4.6	CY74FCT245ATPC	P5	20-Lead (300-Mil) Molded DIP	Commercial
	CY74FCT245ATQCT	Q5	20-Lead (150-Mil) QSOP	
	CY74FCT245ATSOC/SOCT	S5	20-Lead (300-Mil) Molded SOIC	
4.9	CY54FCT245ATDMB	D6	20-Lead (300-Mil) CerDIP	Military
	CY54FCT245ATLMB	L61	20-Square Leadless Chip Carrier	
7.0	CY74FCT245TQCT	Q5	20-Lead (150-Mil) QSOP	Commercial
	CY74FCT245TSOC/SOCT	S5	20-Lead (300-Mil) Molded SOIC	
7.5	CY54FCT245TDMB	D6	20-Lead (300-Mil) CerDIP	Military
	CY54FCT245TLMB	L61	20-Square Leadless Chip Carrier	

Notes:
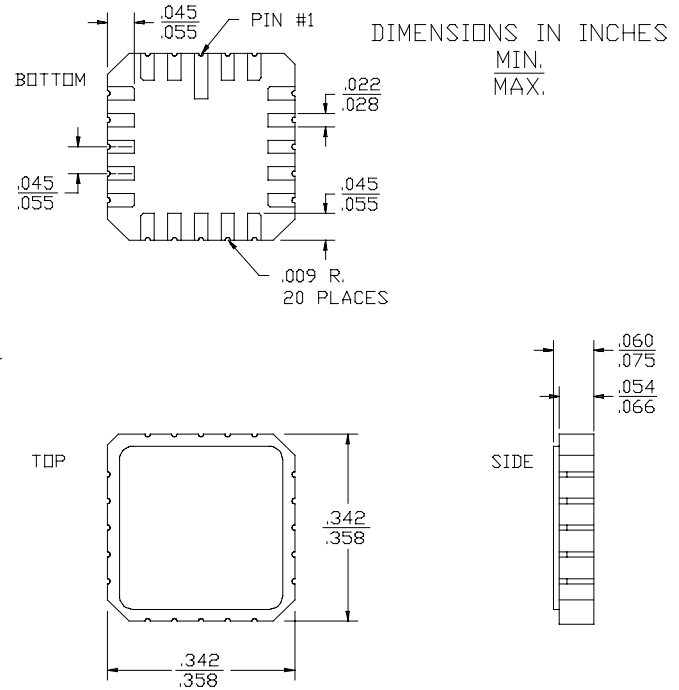12. Minimum limits are specified but not tested on Propagation Delays.
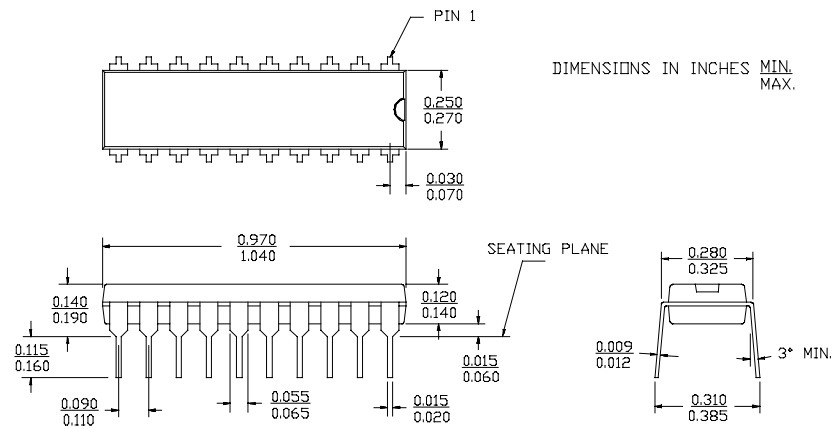13. See "Parameter Measurement Information" in the General Information section.

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Package Diagrams

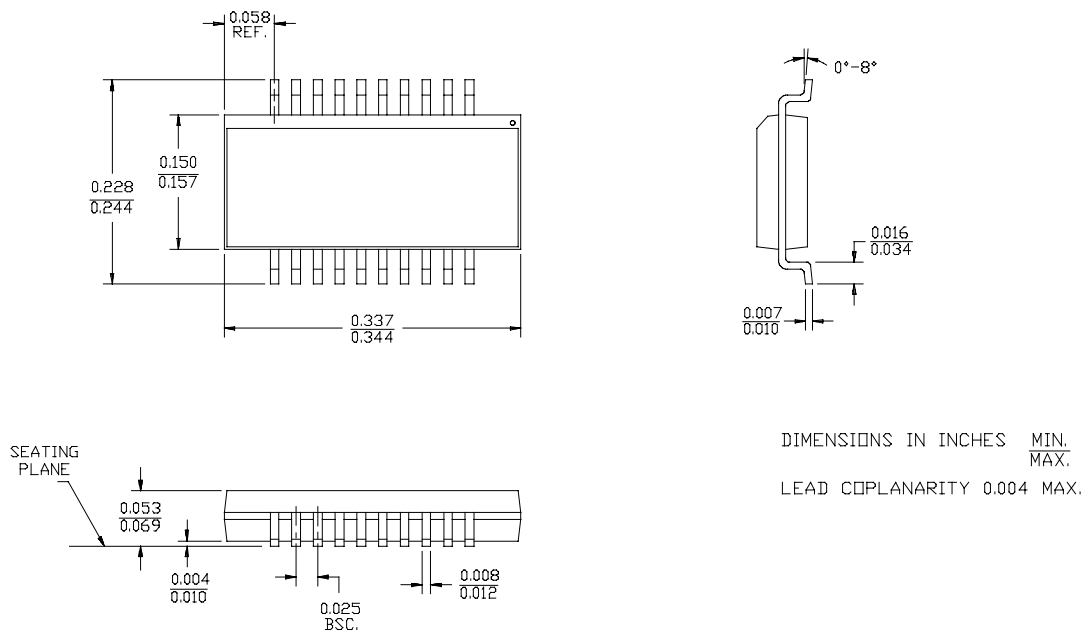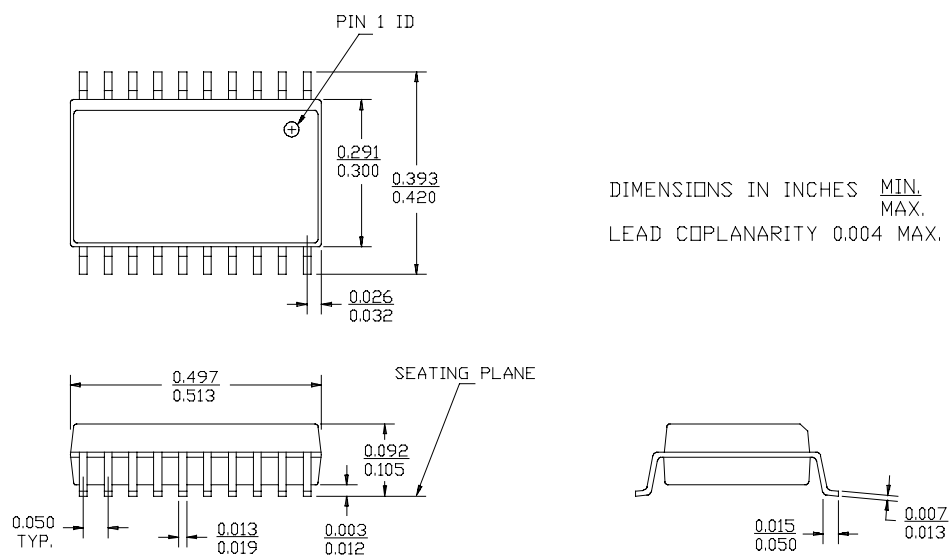**20-Lead (300-Mil) CerDIP D6**
MIL−STD−1835 D−8 Config.A
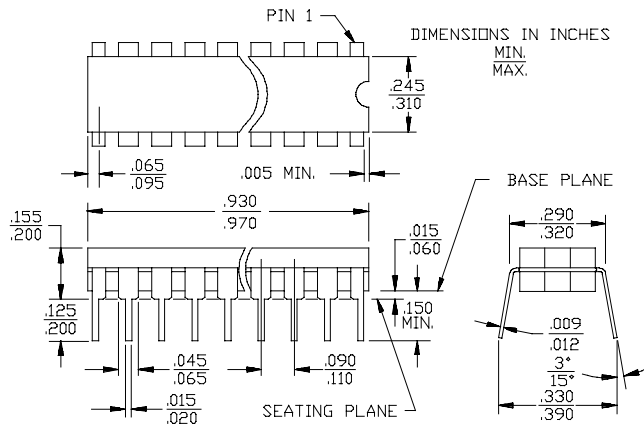
20-Pin Square Leadless Chip Carrier L61
MIL−STD−1835 C−2A

20-Lead (300-Mil) Molded DIP P5

Package Diagrams (continued)

20-Lead Quarter Size Outline Q5

DIMENSIONS IN INCHES $\frac{MIN.}{MAX.}$

LEAD COPLANARITY 0.004 MAX.

20-Lead (300-Mil) Molded SOIC S5

PIN 1 ID

DIMENSIONS IN INCHES $\frac{MIN.}{MAX.}$

LEAD COPLANARITY 0.004 MAX.

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